

500mW High Power Laser Diode

Description

SLD303V are gain-guided, high-power laser diodes fabricated by MOCVD.

MOCVD: Metal Organic Chemical Vapor Deposition

Features

- High power
Recommended power output $P_o = 450\text{mW}$
- Small operating current

Applications

- Solid state laser excitation
- Medical use

Structure

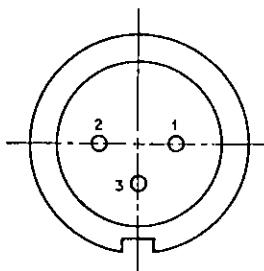
GaAlAs double-hetero laser diode

Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)

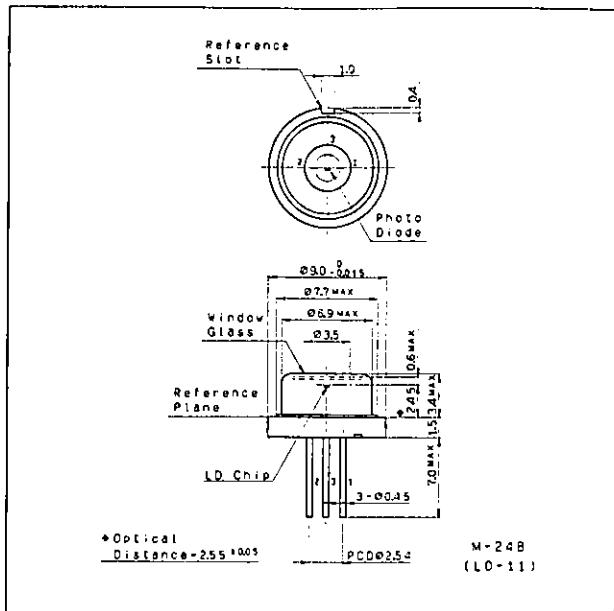
• Radiant power output	P_o	500	mW
• Reverse voltage	V_R	LD 2	V
		PD 15	V
• Operating temperature	T_{opr}	-10 to +30	°C
• Storage temperature	T_{stg}	-40 to +85	°C

Pin Configuration (Bottom View)

No.	Function
1	Laser diode cathode
2	Photodiode anode
3	Common

**Package Outline**

Unit: mm



Optical and Electrical Characteristics

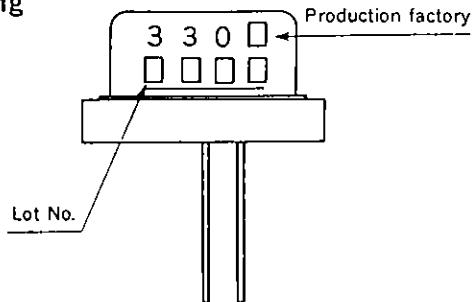
 $T_c = 25^\circ C$

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Threshold current	I_{th}			450	600	mA
Operating current	I_{op}	$P_o = 450\text{mW}$		950	1500	mA
Operating voltage	V_{op}	$P_o = 450\text{mW}$		1.9	3.0	V
Wavelength*	λ_p	$P_o = 450\text{mW}$	770		840	nm
Monitor current	I_{mon}	$P_o = 450\text{mW}$ $V_R = 10V$		0.8		mA
Radiation angle (F. W. H. M)	Perpendicular Parallel	$\theta \perp$ θ_{ll}	$P_o = 450\text{mW}$	28 12	40 17	degree
Positional accuracy	Position Angle	$\Delta X, \Delta Y$ $\Delta \phi \perp$	$P_o = 450\text{mW}$		± 50 ± 3	μm degree
Slope efficiency	η_p	$P_o = 450\text{mW}$	0.65	0.9		mW/mA

*Wavelength Selection Classification

Type	Wavelength (nm)
SLD303V-1	785 ± 15
SLD303V-2	810 ± 10
SLD303V-3	830 ± 10
SLD303V-21 -24 -25	798 ± 3 807 ± 3 810 ± 3

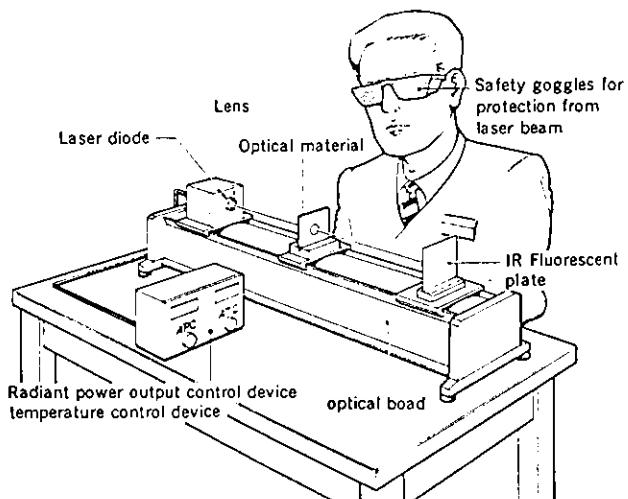
Marking



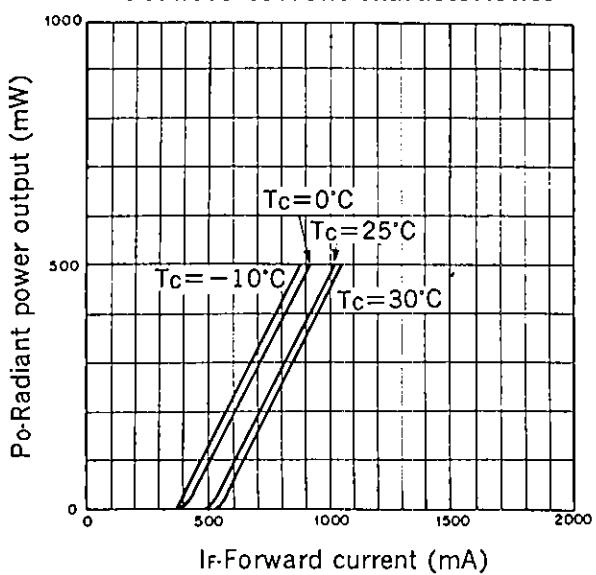
Precautions

Eye protection against laser beams

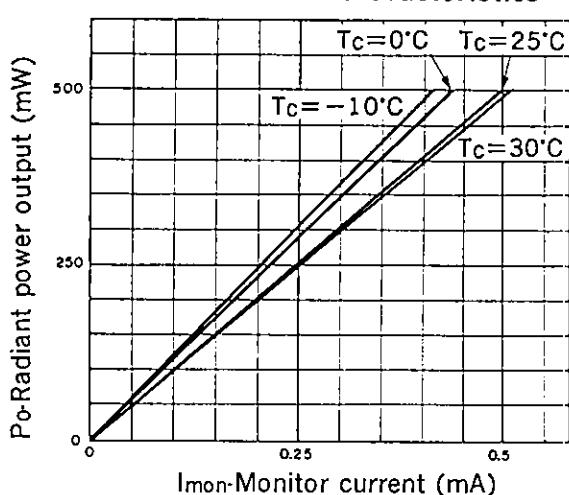
The optical output of laser diodes ranges from several milliwatts to one watt. However the optical density of the laser beam at the diode chip reaches 1 megawatt per square centimeter. Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.



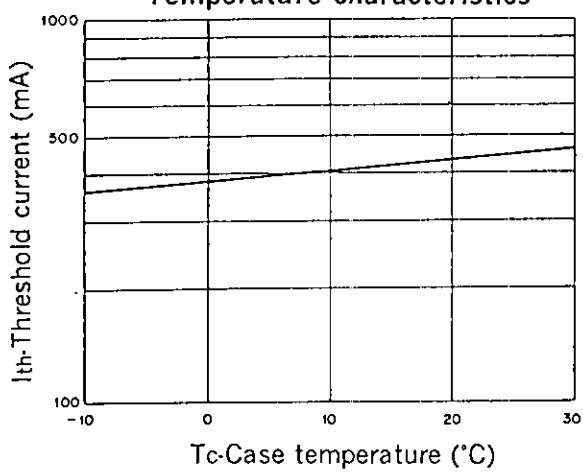
**Radiant power output vs.
Forward current characteristics**



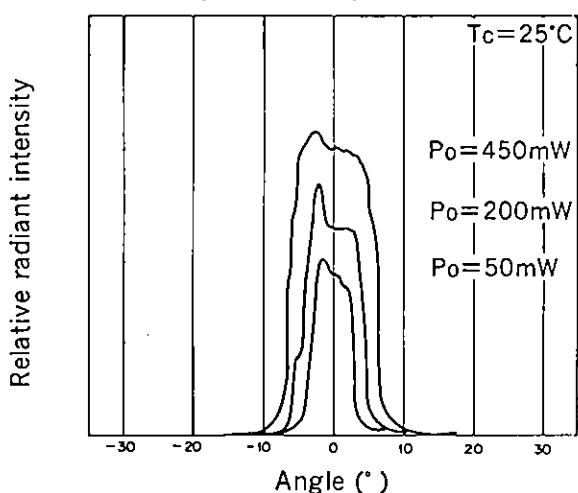
**Radiant power output vs.
Monitor current characteristics**



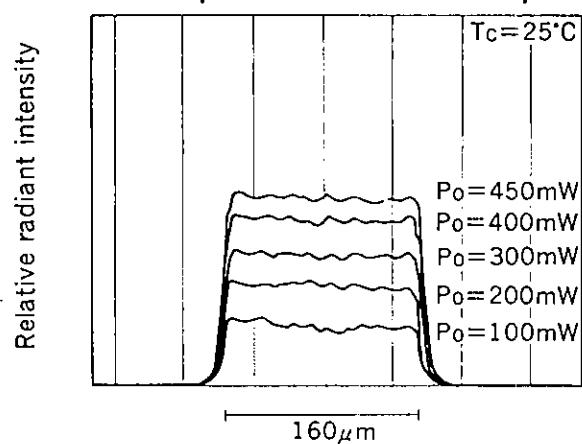
**Threshold current vs.
Temperature characteristics**



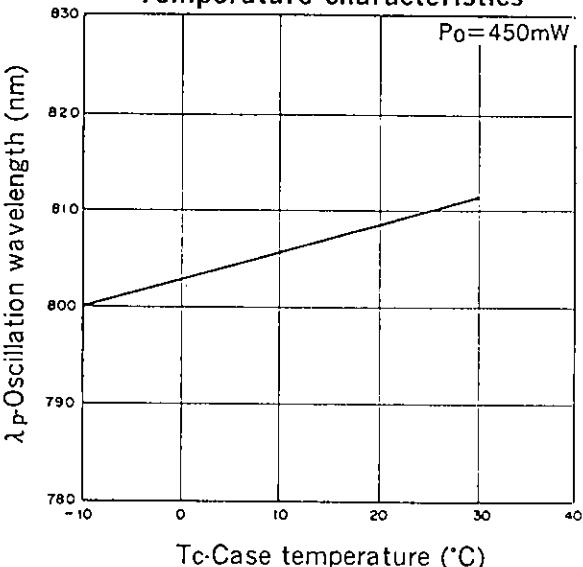
**Power dependence of far field pattern
(parallel to junction)**



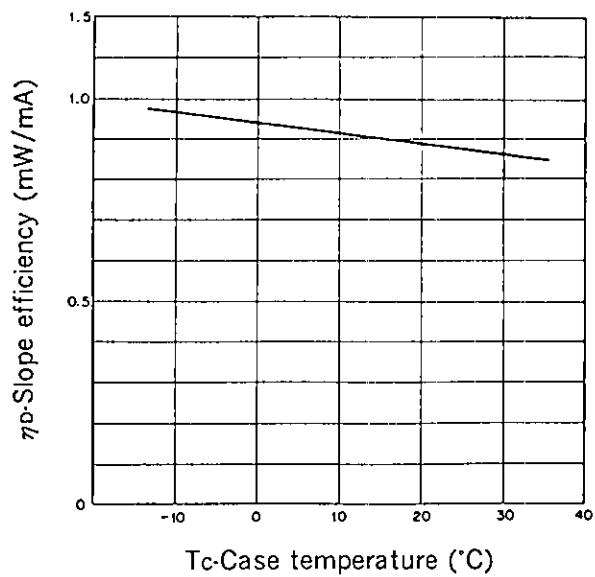
Power dependence of near field pattern



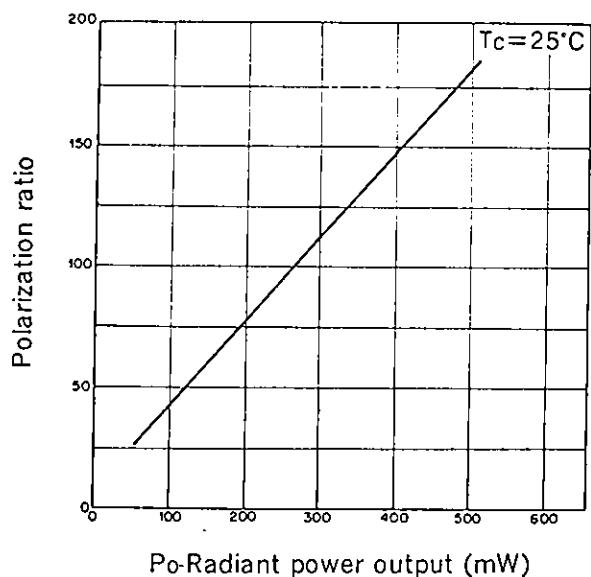
**Oscillation wavelength vs.
Temperature characteristics**



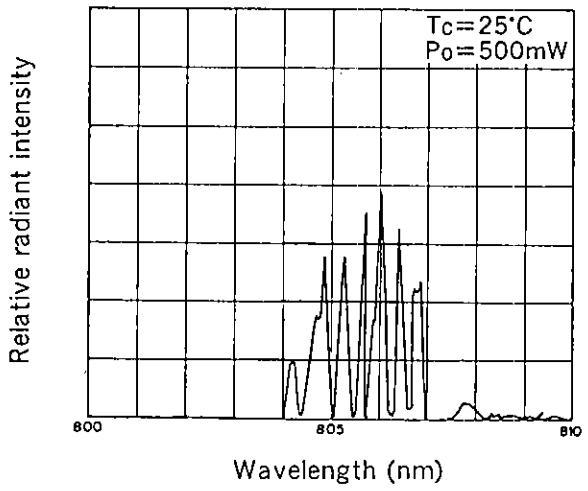
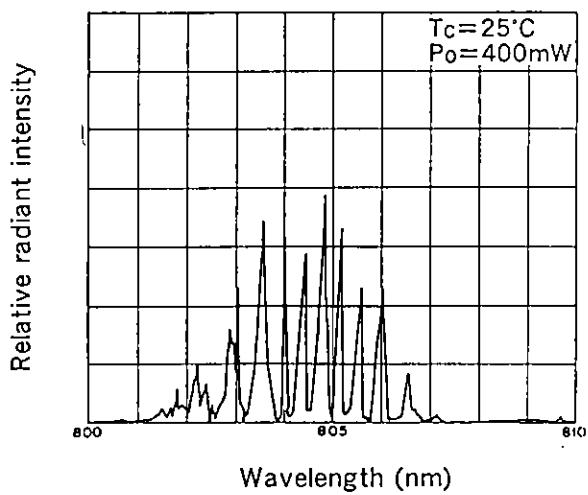
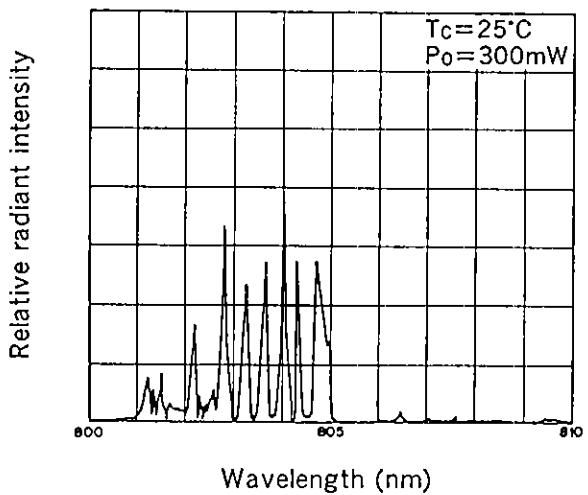
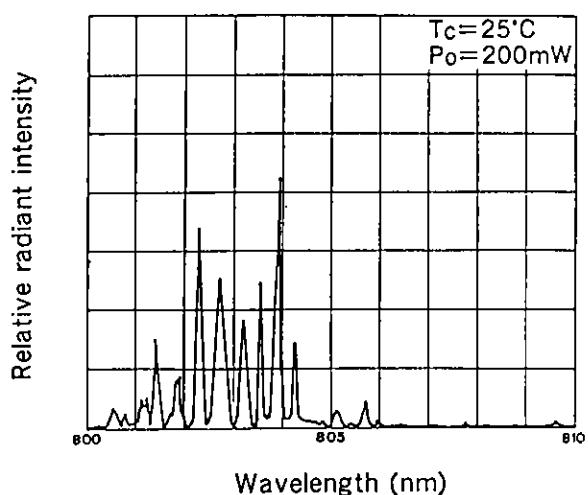
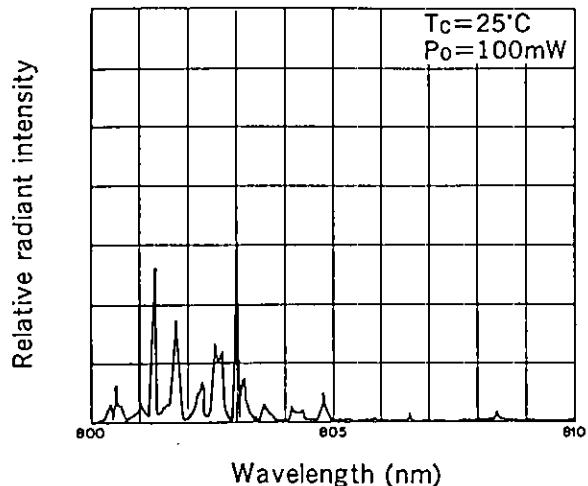
Slope efficiency vs.
Temperature characteristics

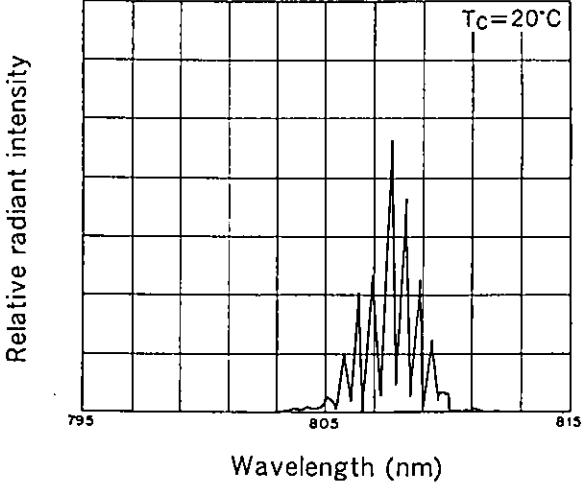
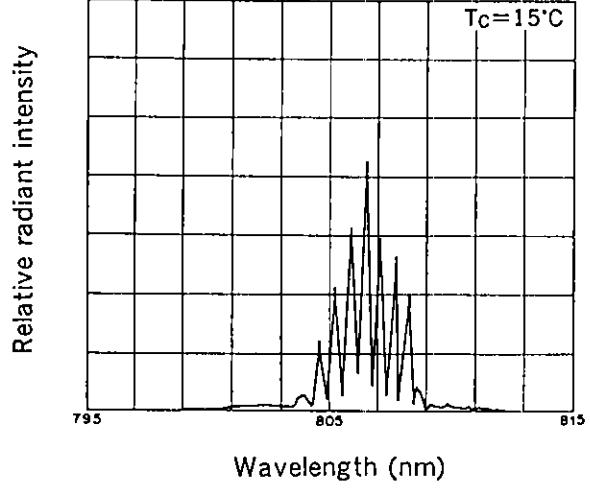
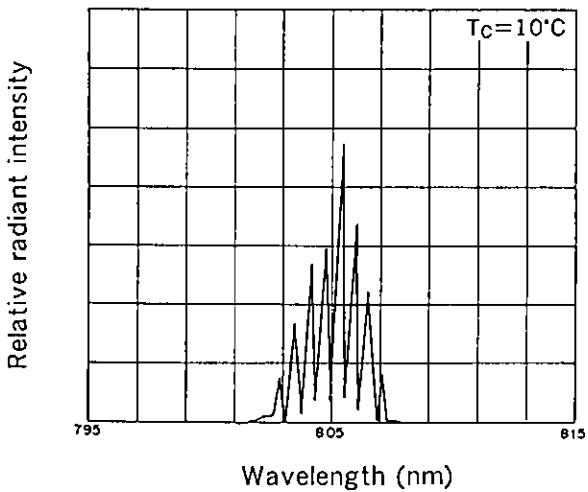
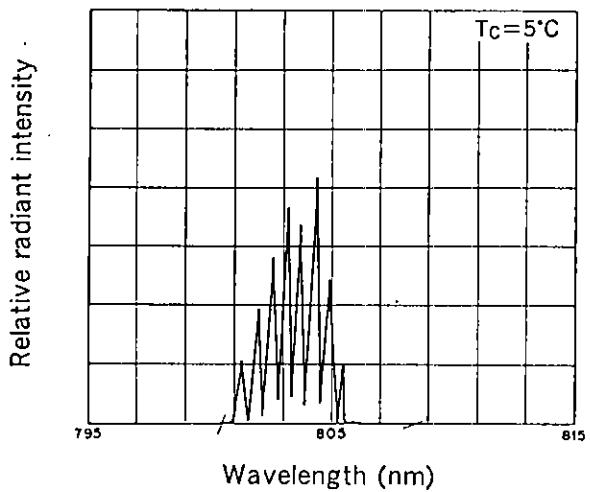
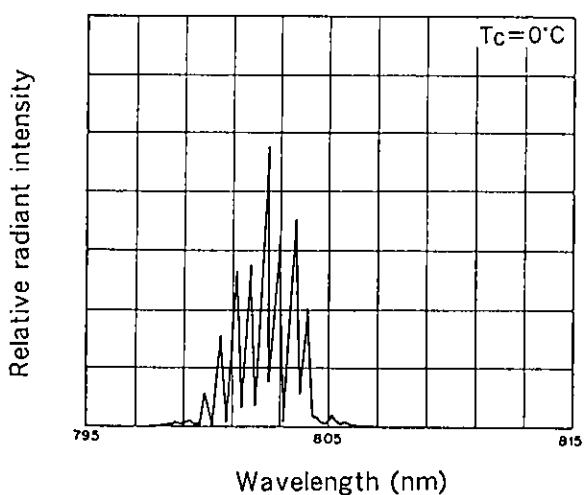
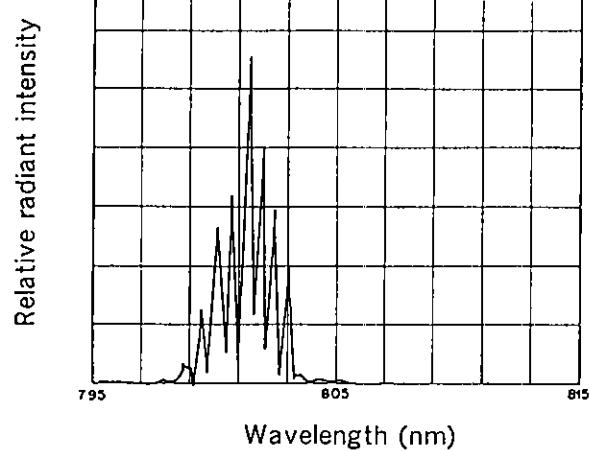


Power dependence of polarization ratio

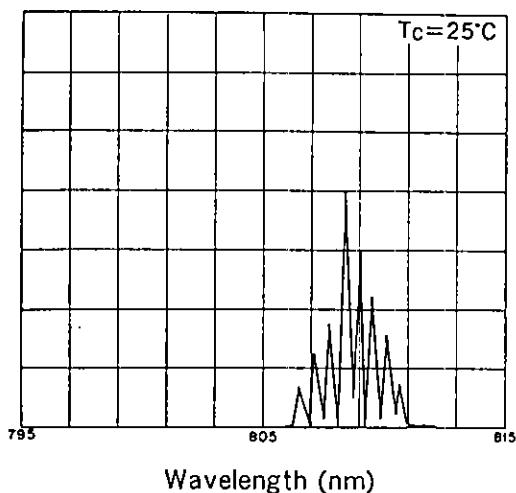


Power dependence of wavelength

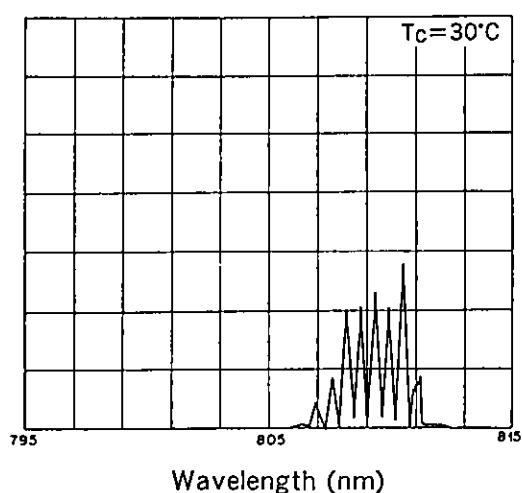


Temperature dependence of wavelength ($P_0=450\text{mW}$)

Relative radiant intensity

 $T_c = 25^\circ\text{C}$

Relative radiant intensity

 $T_c = 30^\circ\text{C}$